

## TO- 277 Plastic-Encapsulate Diodes

### Schottky Rectifier Diode

#### Features:

- $I_{F(AV)}$  10A
- $V_{RRM}$  100V
- High surge current capability
- Low peak forward voltage

#### Application:

- Rectifier

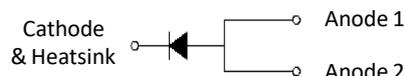
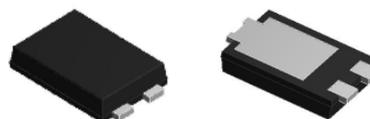
#### Marking

- SB10100L

#### Limiting Values(Absolute Maximum Rating)

| Item                                 | Symbol      | Unit        | Test Conditions                                      | KW10100L   |
|--------------------------------------|-------------|-------------|--|------------|
| Repetitive Peak Reverse Voltage      | $V_{RRM}$   | V           |  | 100        |
| Maximum RMS Voltage                  | $V_{RMS}$   | V           |  | 70         |
| Average Forward Current              | $I_{F(AV)}$ | A           | 60Hz Half-sine wave ,<br>Resistance load , TL(Fig.1) | 10         |
| Surge(Non-repetitive)Forward Current | $I_{FSM}$   | A           | 60Hz Half-sine wave ,<br>1 cycle , $T_a=25^{\circ}C$ | 250        |
| Junction Temperature                 | $T_J$       | $^{\circ}C$ |  | -55 ~ +150 |
| Storage Temperature                  | $T_{STG}$   | $^{\circ}C$ |  | -55 ~ +150 |

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#### Electrical Characteristics (T=25°C Unless otherwise specified)

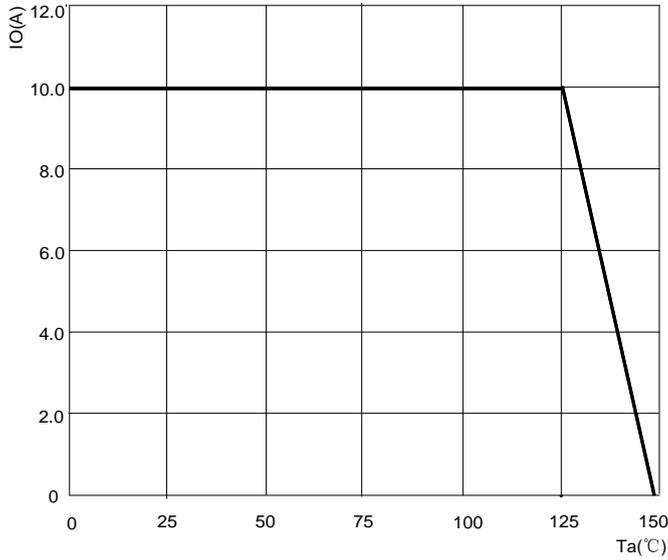
| Item                        | Symbol           | Unit          | Test Condition                |                    | KW10100L  |           |
|-----------------------------|------------------|---------------|-------------------------------|--------------------|-----------|-----------|
| Peak Forward Voltage        | $V_F$            | V             | $I_F=10.0A$                   | $T_a=25^{\circ}C$  | 0.67(TYP) | 0.70(MAX) |
|                             |                  |               |                               | $T_a=125^{\circ}C$ | 0.59(TYP) | 0.64(MAX) |
| Peak Reverse Current        | $I_{RRM1}$       | mA            | $V_{RM}=V_{RRM}$              | $T_a=25^{\circ}C$  | 0.02(TYP) | 0.08(MAX) |
|                             | $I_{RRM2}$       |               |                               | $T_a=125^{\circ}C$ | 10(TYP)   | 20(MAX)   |
| Thermal Resistance(Typical) | $R_{\theta J-A}$ | $^{\circ}C/W$ | Between junction and ambient  |                    | 80        |           |
|                             | $R_{\theta J-L}$ |               | Between junction and terminal |                    | 5         |           |
| Typical junction            | $C_J$            | nF            | $V_R=4.0 V, f=1 MHz$          |                    | 0.95      |           |

#### Notes:

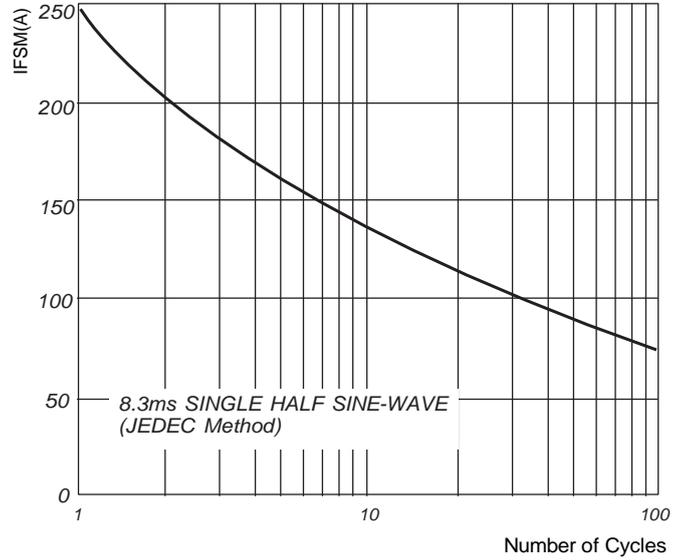
Thermal resistance from junction to ambient and from junction to lead mounted on P.C.B. with 0.3" x 0.3" (8.0 mm x 8.0 mm) copper pad areas

### Typical Characteristics

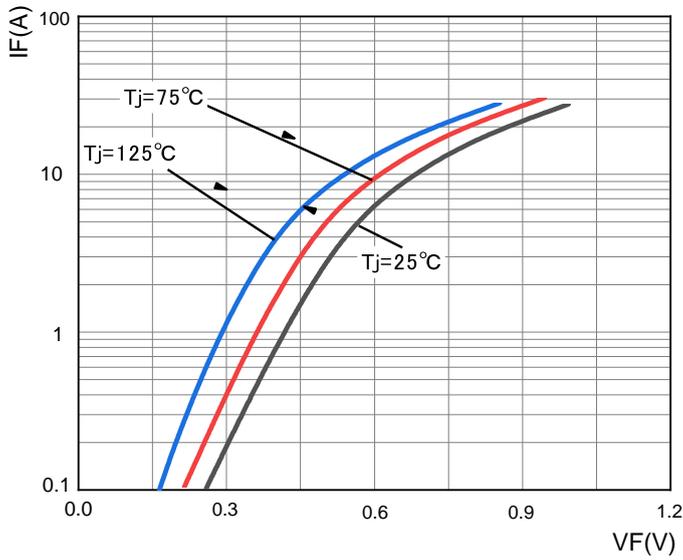
**FIG.1: FORWARD CURRENT DERATING CURVE**



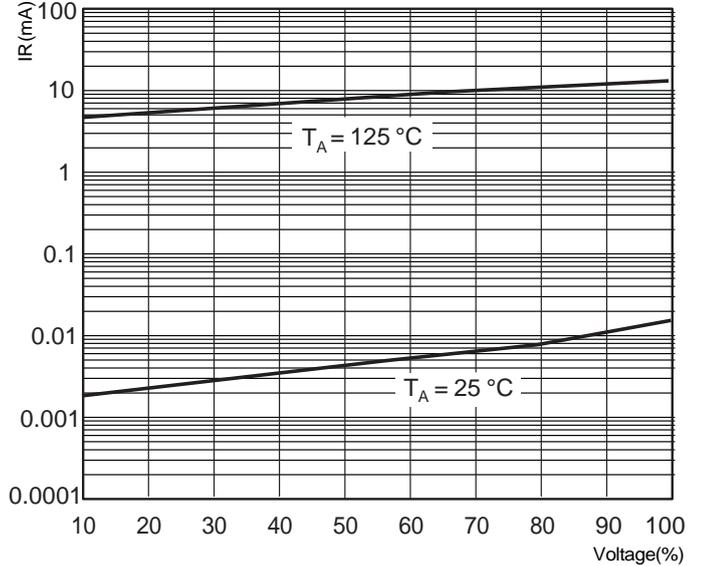
**FIG.2: MAXIMUM NON-REPETITIVE FORWARD SURGE CURRENT**



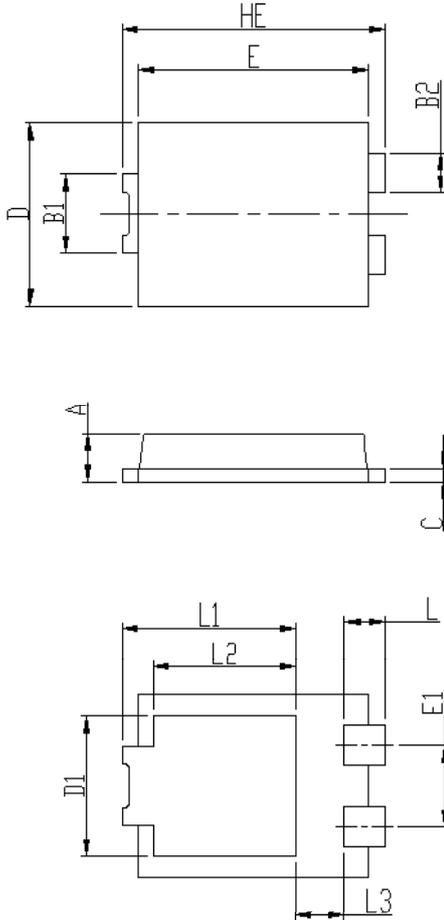
**FIG.3: INSTANTANEOUS FORWARD CHARACTERISTICS**



**FIG.4: TYPICAL REVERSE CHARACTERISTICS**

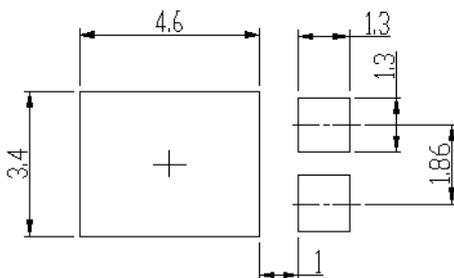


**TO- 277 Package Outline Dimensions**



| DIM | Unit: mm  |     | Unit: inch |       |
|-----|-----------|-----|------------|-------|
|     | MIN       | MAX | MIN        | MAX   |
| HE  | 6.4       | 6.6 | 0.252      | 0.260 |
| E   | 5.6       | 5.8 | 0.220      | 0.228 |
| D   | 4.1       | 4.3 | 0.161      | 0.169 |
| B1  | 1.7       | 1.9 | 0.067      | 0.075 |
| B2  | 0.8       | 1   | 0.031      | 0.039 |
| A   | 1.05      | 1.2 | 0.041      | 0.047 |
| C   | 0.3       | 0.4 | 0.012      | 0.016 |
| L   | 0.85      | 1.1 | 0.033      | 0.043 |
| L1  | 4.2       | 4.4 | 0.165      | 0.173 |
| L2  | 3.52 Typ. |     | 0.139 Typ. |       |
| L3  | 1.1       | 1.4 | 0.043      | 0.055 |
| D1  | 3         | 3.3 | 0.118      | 0.130 |
| E1  | 1.86 Typ. |     | 0.073 Typ. |       |

**TO- 277 Suggested Pad Layout**



**Note:**

1. Controlling dimension: in millimeters.
2. General tolerance:  $\pm 0.05$ mm.
3. The pad layout is for reference purposes only.